



SOT223 N-CHANNEL ENHANCEMENT MODE VERTICAL DMOSFET

## **Product Summary**

| BV <sub>DSS</sub> | Max R <sub>DS(ON)</sub>    | Max I <sub>D</sub><br>T <sub>A</sub> = +25°C |  |
|-------------------|----------------------------|--|--|
| 240V              | $5.5\Omega @ V_{GS} = 10V$ | 500mA  |  |

# **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Earth Recall and Dialing Switches
- Electronic Hook Switches
- Battery Powered Equipment
- Telecoms and High Voltage DC-DC Convertors

#### **Features and Benefits**

- 240 Volt BVDS
- Extremely Low R<sub>DS(ON)</sub>=4.3Ω
- Low Threshold and Fast Switching
- Lead-Free Finish; RoHS Compliant (Notes 1& 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

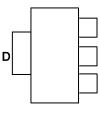
## **Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)



SOT223 (Type DN)

Top View

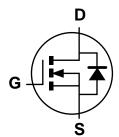


S

D

G

Pin Out Top-View



Equivalent Circuit

## Ordering Information (Note 5)

| Part Number | Compliance | Case             | Packaging |
|-------------|------------|------------------|-----------|
| ZVN4424GTA  | Standard   | SOT223 (Type DN) | 1,000     |
| ZVN4424GQTA | Automotive | SOT223 (Type DN) | 1,000     |

EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

ZVN 4424 = Product Type Marking Code

Y or  $\overline{Y}$  = Last Digit of Year (ex: 8 = 2018)

WW or  $\overline{W}W$  = Week Code (01 to 53)

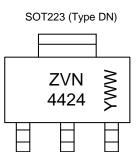
YWW = Date Code Marking

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to https://www.diodes.com/quality/.

For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**

Notes:



ZVN4424G Datasheet Number: DS33378 Rev. 7 - 2



# **Maximum Ratings** ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

| Characteristic           | Symbol           | Value | Unit |
|--------------------------|------------------|-------|------|
| Drain-Source Voltage     | V <sub>DSS</sub> | 240   | V    |
| Gate-Source Voltage      | V <sub>GS</sub>  | ±40   | V    |
| Continuous Drain Current | I <sub>D</sub>   | 500   | mA   |
| Pulsed Drain Current     | I <sub>DM</sub>  | 1.5   | A    |

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                            | Symbol               | Value       | Unit |
|---|----------------------|-------------|------|
| Power Dissipation at $T_A = +25^{\circ}C$ | P <sub>TOT</sub>     | 2.5         | W    |
| Operating and Storage Temperature Range   | TJ, T <sub>STG</sub> | -55 to +150 | °C   |

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

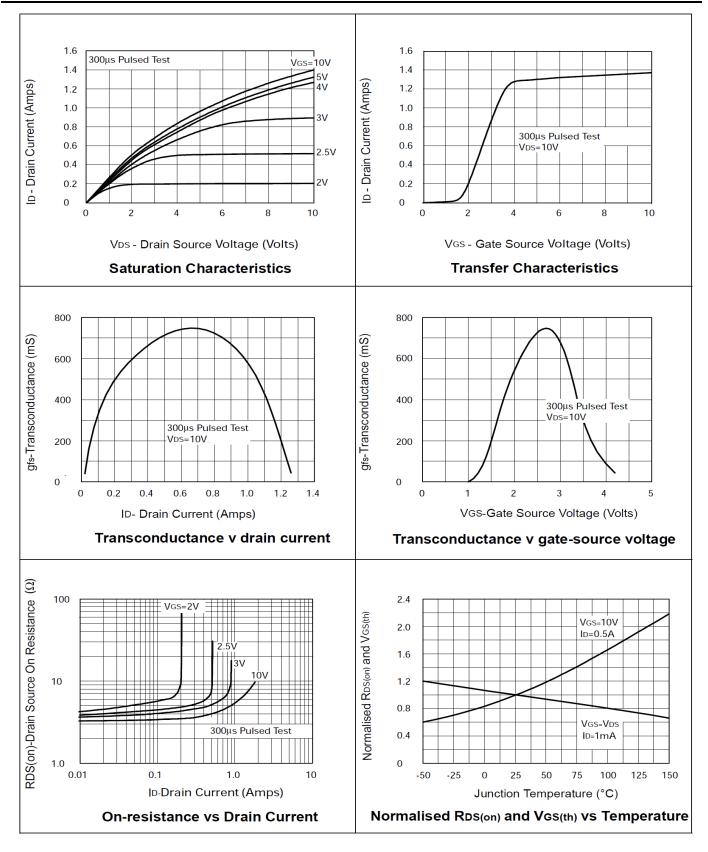
| Characteristic                                   | Symbol              | Min | Тур  | Max                         | Unit | Test Condition   |  |
|--|---------------------|-----|------|-----------------------------|------|--|--|
| OFF CHARACTERISTICS                              |                     |     |      |                             |      |  |  |
| Drain-Source Breakdown Voltage                   | BV <sub>DSS</sub>   | 240 | _    | _                           | V    | $I_D = 1mA$ , $V_{GS} = 0V$  |  |
| Zero Gate Voltage Drain Current                  | I <sub>DSS</sub>    | _   | _    | 10                          | μA   | $V_{DS} = 240V, V_{GS} = 0V$   |  |
| Gate-Body Leakage                                | I <sub>GSS</sub>    |     |      | 100<br>100                  | nA   | $V_{DS} = 190V, V_{GS} = 0V, T_A = +125^{\circ}C$<br>$V_{GS} = \pm 40V, V_{DS} = 0V$ |  |
| Gate-Source Threshold Voltage                    | V <sub>GS(TH)</sub> | 0.8 | 1.3  | 1.8                         | V    | $I_D = 1 \text{mA}, V_{DS} = V_{GS}$   |  |
| ON CHARACTERISTICS                               |                     |     |      |                             |      |  |  |
| On-State Drain Current (Note 6)                  | I <sub>D(ON)</sub>  | 0.8 | 1.4  | _                           | Α    | $V_{DS} = 10V, V_{GS} = 10V$   |  |
| Statia Drain Source On State Desistance (Note 6) | <u> </u>            | 5.5 | Ω    | $V_{GS} = 10V, I_D = 500mA$ |      |  |  |
| Static Drain-Source On-State Resistance (Note 6) | R <sub>DS(ON)</sub> | _   | 4.3  | 6                           | Ω    | V <sub>GS</sub> = 2.5V, I <sub>D</sub> = 500mA                                       |  |
| Forward Transconductance (Notes 6 & 7)           | <b>g</b> fs         | 0.4 | 0.75 | _                           | S    | V <sub>DS</sub> = 10V, I <sub>D</sub> = 0.5A   |  |
| DYNAMIC CHARACTERISTICS                          |                     |     |      |                             |      | ·  |  |
| Input Capacitance (Note 7)                       | Ciss                | _   | 110  | 200                         | pF   | V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V<br>f = 1MHz                              |  |
| Output Capacitance (Note 7)                      | Coss                | _   | 15   | 25                          | pF   |  |  |
| Reverse Transfer Capacitance (Note 7)            | Crss                | _   | 3.5  | 15                          | pF   |  |  |
| Turn-On Delay Time (Notes 7 & 8)                 | t <sub>D(ON)</sub>  | _   | 2.5  | 5                           | ns   |  |  |
| Turn-On Rise Time (Notes 7 & 8)                  | t <sub>R</sub>      | _   | 5    | 8                           | ns   | V <sub>DD</sub> = 50V, V <sub>GEN</sub> = 10V<br>I <sub>D</sub> = 0.25A              |  |
| Turn-Off Delay Time (Notes 7 & 8)                | t <sub>D(OFF)</sub> | _   | 40   | 60                          | ns   |  |  |
| Turn-Off Fall Time (Notes 7 & 8)                 | t <sub>F</sub>      | _   | 16   | 25                          | ns   |  |  |

Measured under pulsed conditions. Width=300µs. Duty cycle ≤ 2%.
Sample test.

8. Switching times measured with 50  $\!\Omega$  source impedance and <5ns rise time on a pulse generator.

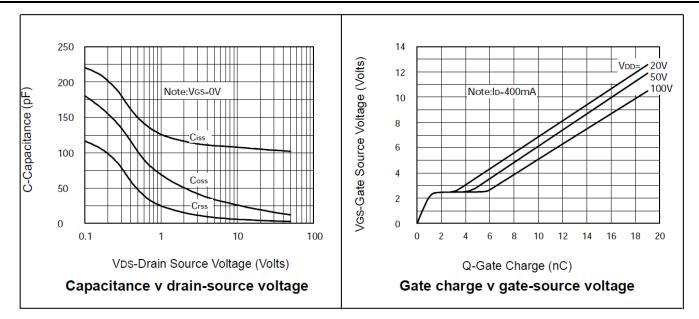


# **Typical Characteristics**





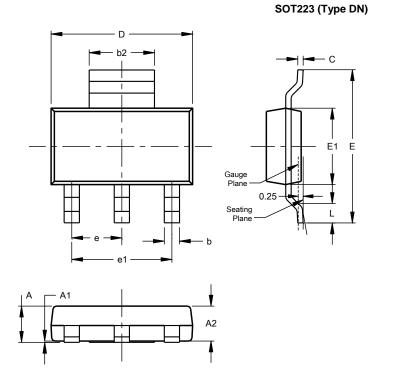
# Typical Characteristics (Cont.)





# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

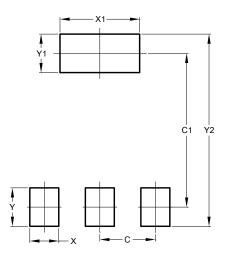


| SOT223 (Type DN)     |      |      |      |  |
|----------------------|------|------|------|--|
| Dim                  | Min  | Max  | Тур  |  |
| Α                    |      | 1.70 |      |  |
| A1                   | 0.01 | 0.15 |      |  |
| A2                   | 1.50 | 1.68 | 1.60 |  |
| b                    | 0.60 | 0.80 | 0.70 |  |
| b2                   | 2.90 | 3.10 |      |  |
| c                    | 0.20 | 0.32 |      |  |
| D                    | 6.30 | 6.70 |      |  |
| ш                    | 6.70 | 7.30 |      |  |
| E1                   | 3.30 | 3.70 |      |  |
| e                    |      |      | 2.30 |  |
| e1                   |      |      | 4.60 |  |
| L                    | 0.85 |      |      |  |
| All Dimensions in mm |      |      |      |  |

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT223 (Type DN)



| Dimensions | Value (in mm) |
|------------|---------------|
| С          | 2.30          |
| C1         | 6.40          |
| Х          | 1.20          |
| X1         | 3.30          |
| Y          | 1.60          |
| Y1         | 1.60          |
| C2         | 8.00          |



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